

TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC7MH153FK

## Dual 4-Channel Multiplexer

The TC7MH153FK is an advanced high speed CMOS dual 4-channel multiplexers fabricated with silicon gate C<sup>2</sup>MOS technology.

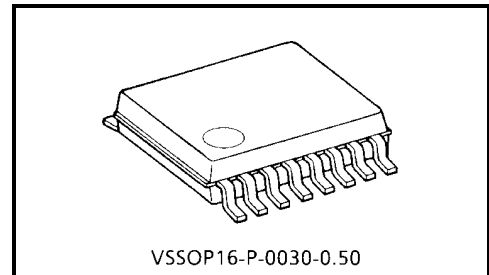
It achieves the high speed operation similar to equivalent bipolar schottky TTL while maintaining the CMOS low power dissipation.

Each of these data (1C0-1C3, 2C0-2C3) is selected by the two address inputs A and B.

Separate strobe inputs ( $\overline{1G}$ ,  $\overline{2G}$ ) are provided for each of the two four-line sections.

The strobe input ( $\overline{G}$ ) can be used to inhibit the data output; the output is fixed in low level while the strobe input is held high.

An input protection circuit ensures that 0 to 7 V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5 V to 3 V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.



Weight: 0.02 g (typ.)

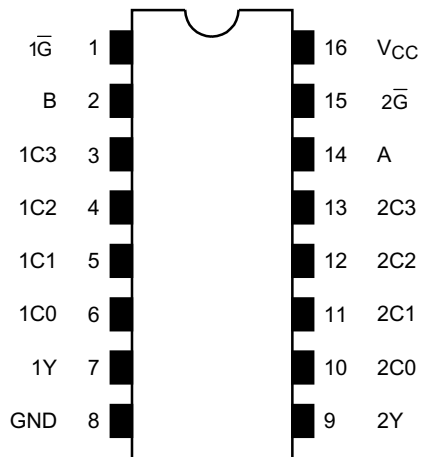
## Features

- High speed:  $t_{pd} = 5.0$  ns (typ.) ( $V_{CC} = 5$  V)
- Low power dissipation:  $I_{CC} = 4$   $\mu$ A (max) ( $T_a = 25^\circ$ C)
- High noise immunity:  $V_{NIH} = V_{NIL} = 28\%$   $V_{CC}$  (min)
- Power down protection is provided on all inputs.
- Balanced propagation delays:  $t_{pLH} \approx t_{pHL}$
- Wide operating voltage range:  $V_{CC (opr)} = 2\sim 5.5$  V
- Pin and function compatible with 74ALS153

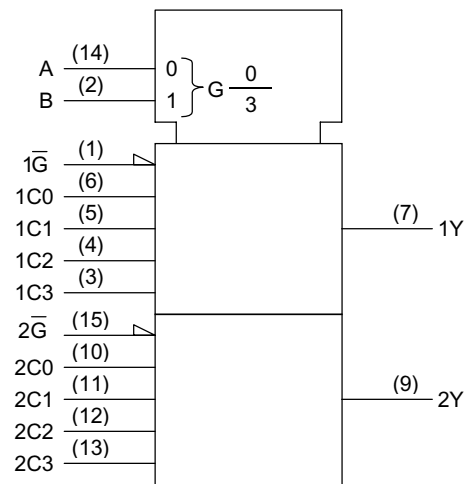
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## Pin Assignment (top view)



## IEC Logic Symbol

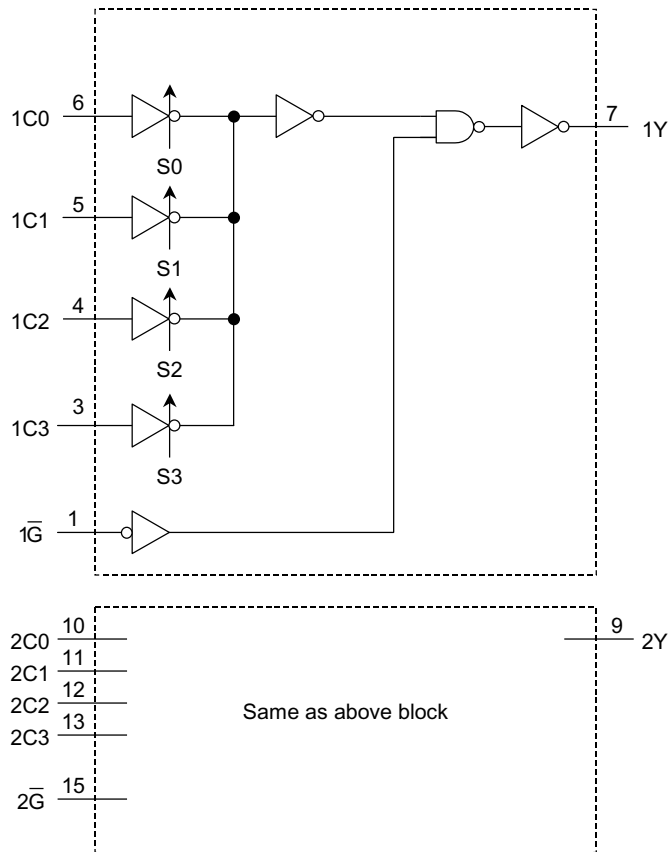
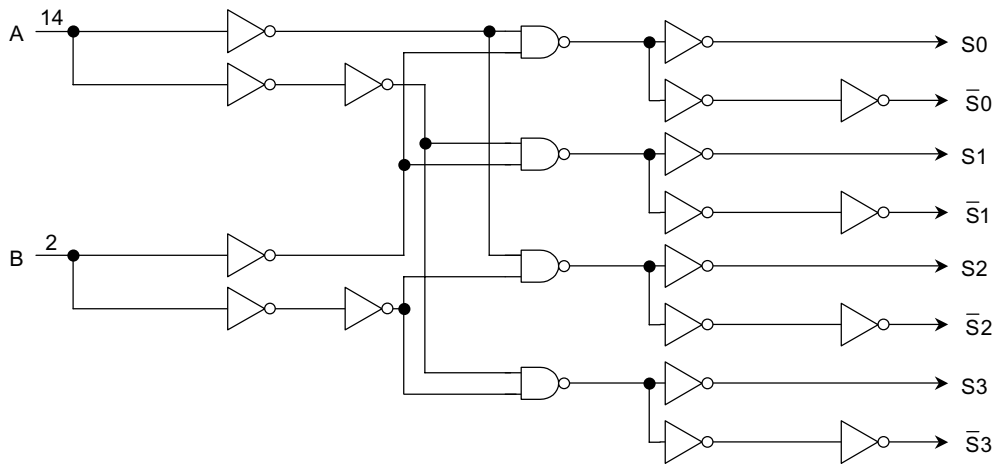


## Truth Table

Select Inputs		Data Inputs				Strobe	Output
B	A	C0	C1	C2	C3	$\bar{G}$	Y
X	X	X	X	X	X	H	L
L	L	L	X	X	X	L	L
L	L	H	X	X	X	L	H
L	H	X	L	X	X	L	L
L	H	X	H	X	X	L	H
H	L	X	X	L	X	L	L
H	L	X	X	H	X	L	H
H	H	X	X	X	L	L	L
H	H	X	X	X	H	L	H

X: Don't care

**System Diagram**



## Maximum Ratings

Characteristics	Symbol	Rating	Unit
Supply voltage range	$V_{CC}$	-0.5~7.0	V
DC input voltage	$V_{IN}$	-0.5~7.0	V
DC output voltage	$V_{OUT}$	-0.5~ $V_{CC} + 0.5$	V
Input diode current	$I_{IK}$	-20	mA
Output diode current	$I_{OK}$	±20	mA
DC output current	$I_{OUT}$	±25	mA
DC $V_{CC}$ /ground current	$I_{CC}$	±50	mA
Power dissipation	$P_D$	180	mW
Storage temperature	$T_{stg}$	-65~150	°C

## Recommended Operating Conditions

Characteristics	Symbol	Rating	Unit
Supply voltage	$V_{CC}$	2.0~5.5	V
Input voltage	$V_{IN}$	0~5.5	V
Output voltage	$V_{OUT}$	0~ $V_{CC}$	V
Operating temperature	$T_{opr}$	-40~85	°C
Input rise and fall time	dt/dv	0~100 ( $V_{CC} = 3.3 \pm 0.3$ V) 0~20 ( $V_{CC} = 5 \pm 0.5$ V)	ns/V

## Electrical Characteristics

### DC Characteristics

Characteristics		Symbol	Test Condition	$T_a = 25^\circ\text{C}$			$T_a = -40\sim 85^\circ\text{C}$		Unit		
				$V_{CC}$ (V)	Min	Typ.	Max	Min		Max	
Input voltage	High level	$V_{IH}$	—	2.0 3.0~5.5	1.50 $V_{CC} \times 0.7$	— —	— —	1.50 $V_{CC} \times 0.7$	— —	V	
	Low level	$V_{IL}$	—	2.0 3.0~5.5	— —	— —	0.50 $V_{CC} \times 0.3$	— —	0.50 $V_{CC} \times 0.3$		
Output voltage	High level	$V_{OH}$	$V_{IN} = V_{IH}$ or $V_{IL}$	$I_{OH} = -50 \mu\text{A}$	2.0 3.0 4.5	1.9 2.9 4.4	2.0 3.0 4.5	— — —	1.9 2.9 4.4	— — —	V
				$I_{OH} = -4 \text{ mA}$	3.0 4.5	2.58 3.94	— —	— —	2.48 3.80	— —	
				$I_{OH} = -8 \text{ mA}$	4.5	3.94	—	—	3.80	—	
	Low level	$V_{OL}$	$V_{IN} = V_{IH}$ or $V_{IL}$	$I_{OL} = 50 \mu\text{A}$	2.0 3.0 4.5	— — —	0 0 0	0.1 0.1 0.1	— — —	0.1 0.1 0.1	
				$I_{OL} = 4 \text{ mA}$	3.0 4.5	— —	— —	0.36 0.36	— —	0.44 0.44	
				$I_{OL} = 8 \text{ mA}$	4.5	—	—	0.36	—	0.44	
Input leakage current		$I_{IN}$	$V_{IN} = 5.5 \text{ V or GND}$	0~5.5	—	—	±0.1	—	±1.0	μA	
Quiescent supply current		$I_{CC}$	$V_{IN} = V_{CC} \text{ or GND}$	5.5	—	—	4.0	—	40.0	μA	

## AC Characteristics (Input: $t_r = t_f = 3$ ns)

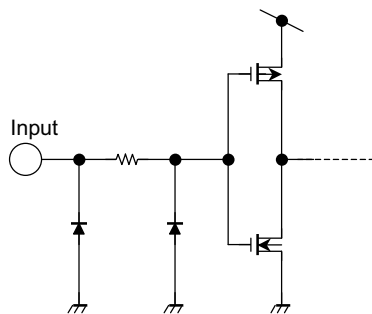
Characteristics	Symbol	Test Condition	Ta = 25°C			Ta = -40~85°C		Unit		
			V <sub>CC</sub> (V)	C <sub>L</sub> (pF)	Min	Typ.	Max		Min	Max
Propagation delay time (C <sub>n</sub> -Y)	$t_{pLH}$ $t_{pHL}$	—	3.3 ± 0.3	15	—	7.7	11.9	1.0	14.0	ns
				50	—	10.2	15.4	1.0	17.5	
			5.0 ± 0.5	15	—	5.0	7.7	1.0	9.0	
				50	—	6.5	9.7	1.0	11.0	
Propagation delay time (A, B-Y)	$t_{pLH}$ $t_{pHL}$	—	3.3 ± 0.3	15	—	10.8	16.7	1.0	19.5	ns
				50	—	13.3	20.2	1.0	23.0	
			5.0 ± 0.5	15	—	6.8	9.9	1.0	11.5	
				50	—	8.3	11.9	1.0	13.5	
Propagation delay time ( $\bar{G}$ -Y)	$t_{pLH}$ $t_{pHL}$	—	3.3 ± 0.3	15	—	6.3	10.1	1.0	12.0	ns
				50	—	8.8	13.6	1.0	15.5	
			5.0 ± 0.5	15	—	4.4	6.4	1.0	7.5	
				50	—	5.9	8.4	1.0	9.5	
Input capacitance	C <sub>IN</sub>	—	—	4	10	—	10	pF		
Power dissipation capacitance	C <sub>PD</sub>	(Note)	—	20	—	—	—	pF		

Note: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

$$I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$$

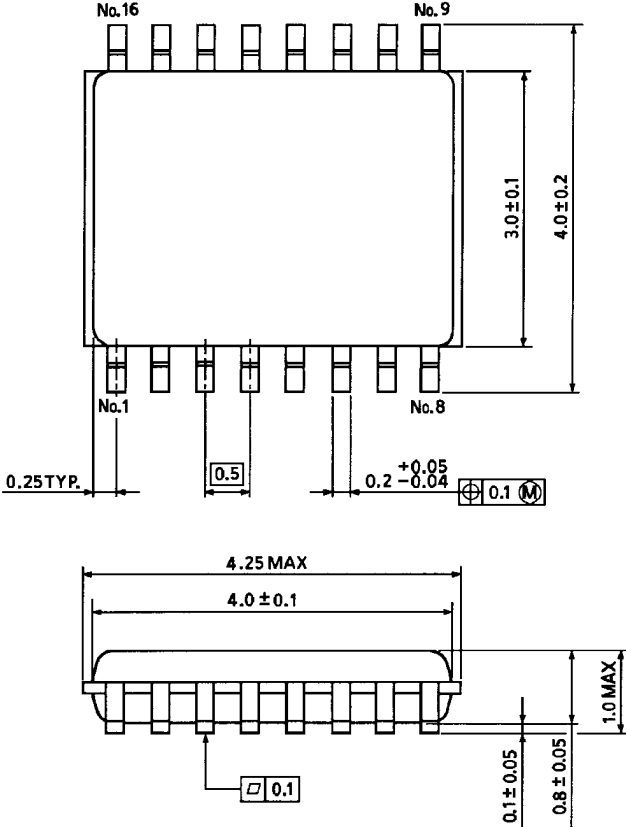
## Input Equivalent Circuit



Package Dimensions

VSSOP16-P-0030-0.50

Unit : mm



Weight: 0.02 g (typ.)